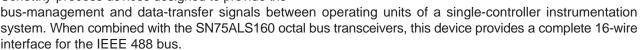
- Suitable for IEEE Standard 488-1978 (GPIB)
- 8-Channel Bidirectional Transceivers
- Designed to Implement Control Bus Interface
- Designed for Single Controller
- High-Speed Advanced Low-Power Schottky Circuitry
- Low Power Dissipation . . . 46 mW Max Per Channel
- Fast Propagation Times . . . 20 ns Max
- High-Impedance pnp Inputs
- Receiver Hysteresis . . . 650 mV Typ
- Bus-Terminating Resistors Provided on Driver Outputs
- No Loading of Bus When Device Is Powered Down (V<sub>CC</sub> = 0)
- Power-Up/Power-Down Protection (Glitch Free)

#### description/ordering information

TheSN75ALS161eight-channelgeneral-purposeinterfacebustransceivershigh-speed,advancedlow-powerSchottky-processdevicesdesignedto



The SN75ALS161 device features eight driver-receiver pairs connected in a front-to-back configuration to form input/output (I/O) ports at both the bus and terminal sides. The direction of data through these driver-receiver pairs is determined by the direction-control (DC) and talk-enable (TE) signals.

The driver outputs general-purpose interface bus (GPIB I/O ports) feature active bus-terminating resistor circuits designed to provide a high impedance to the bus when  $V_{CC} = 0$ . The drivers are designed to handle sink-current loads up to 48 mA. Each receiver features pnp transistor inputs for high input impedance and hysteresis of 400 mV on the commercial part, and 250 mV on the military part, minimum, for increased noise immunity. All receivers have 3-state outputs, to present a high impedance to the terminal when disabled.

The SN75ALS161 is characterized for operation from 0°C to 70°C.

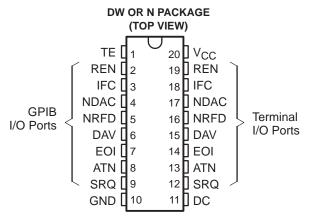
Τ <sub>Α</sub>	PACK	AGE <sup>†</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING									
	PDIP (N)	Tube of 20	SN75ALS161N	SN75ALS161N									
0°C to 70°C		Tube of 25		SN75ALS161DW	7541 0404								
	SOIC (DW)	Reel of 2000	SN75ALS161DWR	75ALS161									

#### ORDERING INFORMATION

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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#### CHANNEL-IDENTIFICATION TABLE

NAME	IDENTITY	CLASS		
DC	Direction Control	Control		
TE	Talk Enable	Control		
ATN	Attention			
SRQ	Service Request			
REN	Remote Enable	Bus		
IFC	Interface Clear	Management		
EOI	End or Identify			
DAV	Data Valid			
NDAC NRFD	Not Data Accepted Not Ready for Data	Data Transfer		

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	RECEIVE/TRANSMIT													
C	ONTRO	LS	BUS	-MANAG	GEMENT	CHANN	NELS	DATA-TR	ANSFER CH	HANNELS				
DC	TE	ATN <sup>†</sup>	ATN <sup>†</sup> SRQ REN IFC EOI (CONTROLLED BY DC)				DAV (CON	NDAC TROLLED E	NRFD BY TE)					
Н	Н	Н	R	т	R	R	Т	-	Р	Р				
Н	Н	L	ĸ	I	ĸ	N	R	I	R	R				
L	L	Н	Ŧ	5	-	-	R	6	-	H				
L	L	L	I	R	I	I	Т	R	I	I				
Н	L	Х	R	Т	R	R	R	R	Т	Т				
L	Н	Х	Т	R	Т	Т	Т	Т	R	R				

FUNCTION TABLE

H = high level, L = low level, R = receive, T = transmit, X = irrelevant

Direction of data transmission is from the terminal side to the bus side, and the direction of data receiving is from the bus side to the terminal side.

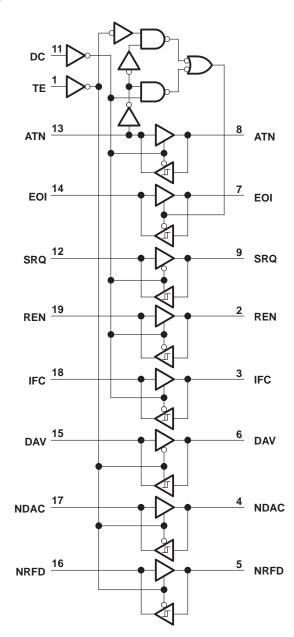
Data transfer is noninverting in both directions.

<sup>†</sup> ATN is a normal transceiver channel that functions additionally as an internal direction control or talk enable for EOI whenever the DC and TE inputs are in the same state. When DC and TE are in opposite states, the ATN channel functions as an independent transceiver only.



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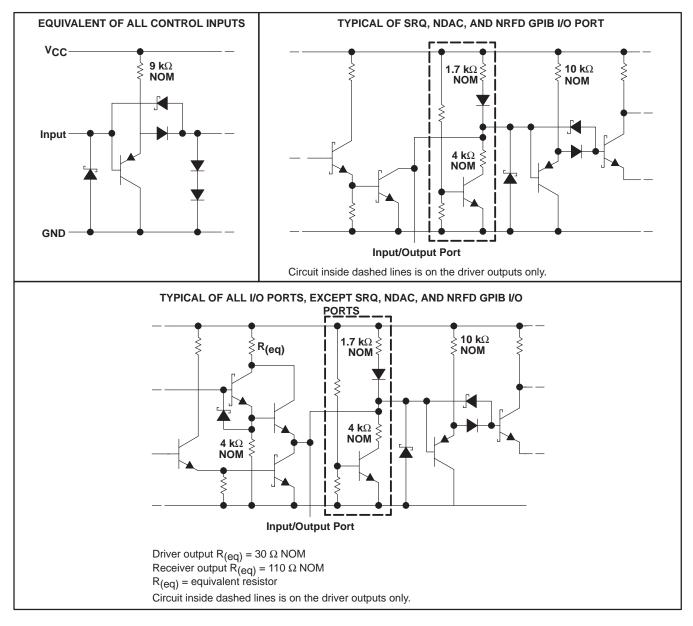
logic diagram (positive logic)





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#### schematics of inputs and outputs





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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, V <sub>CC</sub> (see Note 1)	
Input voltage, V <sub>I</sub>	
Low-level driver output current, I <sub>OL</sub>	
Package thermal impedance, $\theta_{JA}$ (see Notes 2 and 3): DW package	58°C/W
N package	69°C/W
Operating virtual junction temperature, T <sub>J</sub>	
Storage temperature range, T <sub>stg</sub> –	65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal.

- 2. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions

			MIN	NOM	MAX	UNIT
VCC	Supply voltage		4.75	5	5.25	V
VIH	High-level input voltage		2			V
VIL	Low-level input voltage				0.8	V
		Bus ports with pullups active			- 5.2	mA
ЮН	High-level output current	Terminal ports			- 800	μΑ
		Bus ports			48	
IOL	Low-level output current	Terminal ports			16	mA
TA	Operating free-air temperature		0		70	°C



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#### electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TES	T CONDITIONS	st	MIN	TYP‡	MAX	UNIT
VIK	Input clamp voltage		lj = -18 mA				-0.8	-1.5	V
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT+</sub> – V <sub>IT</sub> –)	Bus				0.4	0.65		V
		Terminal	I <sub>OH</sub> = - 800 μA,	V <sub>CC</sub> = MIN	$T_A = 25^{\circ}C$ and MAX	2.7	3.5		
					$T_A = MIN$	2.7	3.5		V
VOH§	High-level output voltage	Bus	l <sub>OH</sub> = – 5.2 mA,	V <sub>CC</sub> = MIN	$T_A = 25^{\circ}C$ and MAX	2.2			V
					$T_A = MIN$	2.2			
Max		Terminal	I <sub>OL</sub> = 16 mA,	$V_{CC} = MIN$			0.3	0.5	V
VOL	Low-level output voltage	Bus	I <sub>OL</sub> = 48 mA,	$V_{CC} = MIN$			0.35	0.5	V
lj	Input current at maximum input voltage	Terminal	V <sub>I</sub> = 5.5 V,	$V_{CC} = MAX$			0.2	100	μΑ
Iн	High-level input current	Terminal and control inputs	V <sub>I</sub> = 2.7 V,	V <sub>CC</sub> = MAX			0.1	20	μΑ
		-	$I_{I(bus)} = 0$			2.5	3	3.7	
VI/O	Voltage at GPIB I/O port		$I_{I(bus)} = 0$			2.5	3	3.7	V
			$I_{I(bus)} = -12 \text{ mA}$					-1.5	
۱ <sub>IL</sub>	Low-level input current	Terminal and control inputs	V <sub>I</sub> = 0.5 V,	$V_{CC} = MAX$			-10	-100	μΑ
			V <sub>I(bus)</sub> = -1.5 V		-1.3				
			VI(bus) = 0.4 V te	o 2.5 V		0		-3.2	
II/O	Current into GPIB I/O port	Power on	$V_{I(bus)} = 2.5 V te$	o 3.7 V				2.5 -3.2	mA
			V <sub>I(bus)</sub> = 3.7 V te	o 5 V		0		2.5	
			$V_{I(bus)} = 5 V to$	5.5 V		0.7		2.5	
		Power off	VCC = 0	$V_{I(bus)} = 0 tc$	o 2.5 V			40	μΑ
los§	Short-circuit output current	Terminal	V <sub>CC</sub> = MAX			-15	-35	-75	mA
·05°	chore onour output outfolk	Bus				-25	-50	-125	
ICC	Supply current		No load,	TE and DC Ic $V_{CC} = MAX$			55	75	mA
CI/O	GPIB I/O port capacitance		$V_{CC} = 0$ to 5 V,	$V_{I/O} = 0$ to 2	V, $f = 1 MHz$		30		pF

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>‡</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C. § V<sub>OH</sub> and I<sub>OS</sub> apply to 3-state outputs only.



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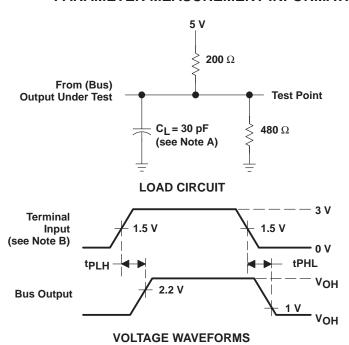
### switching characteristics over recommended operating free-air temperature range, V<sub>CC</sub> = 5 V

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN TYP <sup>†</sup>	MAX	UNIT
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	Terminal	Bus	C <sub>I</sub> = 30 pF,	10	20	
<sup>t</sup> PHL	Propagation delay time, high- to low-level output	Terminal	Dus	See Figure 1	12	20	ns
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	5		CL = 30 pF,	5	10	
<sup>t</sup> PHL	Propagation delay time, high- to low-level output	Bus	Terminal	See Figure 2	7	14	ns
<sup>t</sup> PZH	Output enable time to high level			С <sub>L</sub> = 15 рF,		30	ns
<sup>t</sup> PHZ	Output disable time from high level		Bus (ATN, EOI, REN, IFC, and			20	
<sup>t</sup> PZL	Output enable time to low level	TE or DC	DAV)	See Figure 3		45	
<sup>t</sup> PLZ	Output disable time from low level		,			20	
<sup>t</sup> PZH	Output enable time to high level					30	
<sup>t</sup> PHZ	Output disable time from high level	TE or DC	Terminal	CL = 15 pF,		25	20
<sup>t</sup> PZL	Output enable time to low level	TEOTDC	reminal	See Figure 4		30	ns
<sup>t</sup> PLZ	Output disable time from low level					25	

<sup>†</sup> All typical values are at  $T_A = 25^{\circ}C$ .



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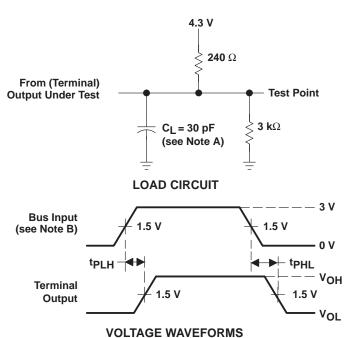
PARAMETER MEASUREMENT INFORMATION

- NOTES: A. CL includes probe and jig capacitance.
  - B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>f</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  8 ns, t<sub>f</sub>  $\leq$  8

#### Figure 1. Terminal-to-Bus Load Circuit and Voltage Waveforms



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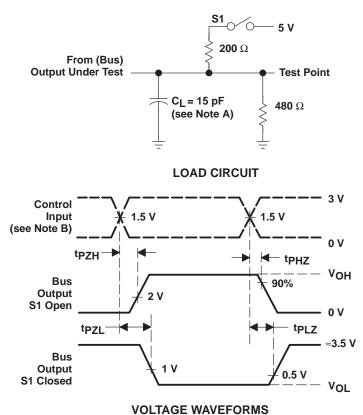
PARAMETER MEASUREMENT INFORMATION

- NOTES: A. CL includes probe and jig capacitance.
  - B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>f</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  6 ns, Z<sub>O</sub> = 50  $\Omega$ .

#### Figure 2. Bus-to-Terminal Load Circuit and Voltage Waveforms



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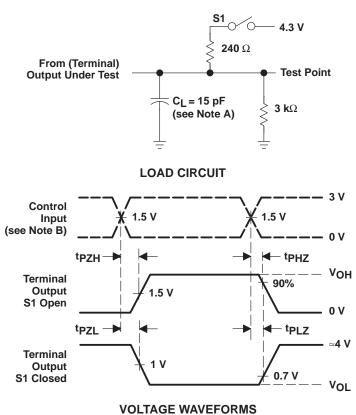
### PARAMETER MEASUREMENT INFORMATION

- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>r</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  6 ns, Z<sub>O</sub> = 50  $\Omega$ .

#### Figure 3. Bus Load Circuit and Voltage Waveforms



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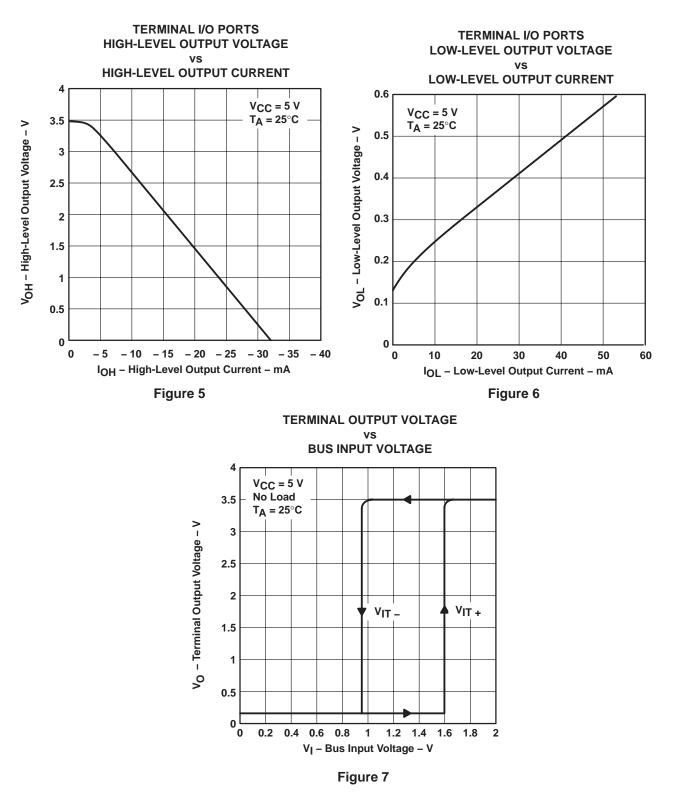
### PARAMETER MEASUREMENT INFORMATION

- NOTES: A. CL includes probe and jig capacitance.
  - B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>f</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  6 ns, Z<sub>Q</sub> = 50  $\Omega$ .

Figure 4. Terminal Load Circuit and Voltage Waveforms



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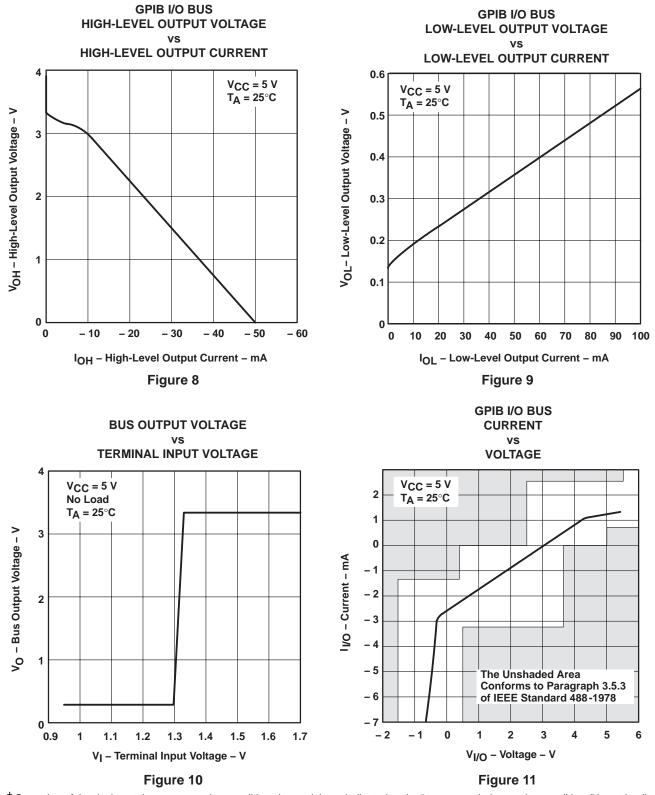


**TYPICAL CHARACTERISTICS<sup>†</sup>** 

<sup>†</sup> Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.



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#### **TYPICAL CHARACTERISTICS<sup>†</sup>**

<sup>†</sup> Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.





#### PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	-		Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	6) (6)	(3)		(4/5)	
SN75ALS161DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS161	Samples
SN75ALS161DWE4	ACTIVE	SOIC	DW	20	25	TBD	Call TI	Call TI	0 to 70		Samples
SN75ALS161DWG4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS161	Samples
SN75ALS161DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS161	Samples
SN75ALS161N	ACTIVE	PDIP	Ν	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75ALS161N	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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# PACKAGE OPTION ADDENDUM

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#### OTHER QUALIFIED VERSIONS OF SN75ALS161 :

• Military : SN55ALS161

NOTE: Qualified Version Definitions:

• Military - QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

Texas **NSTRUMENTS** 

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#### **TAPE AND REEL INFORMATION**





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75ALS161DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1



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# PACKAGE MATERIALS INFORMATION

5-Jan-2022



\*All dimensions are nominal

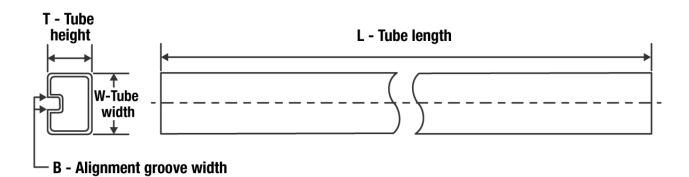
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN75ALS161DWR	SOIC	DW	20	2000	350.0	350.0	43.0	



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5-Jan-2022

### TUBE



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN75ALS161DW	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75ALS161DWE4	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75ALS161DWG4	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75ALS161N	N	PDIP	20	20	506	13.97	11230	4.32

# N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



# **DW0020A**



# **PACKAGE OUTLINE**

### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



# DW0020A

# **EXAMPLE BOARD LAYOUT**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DW0020A

# **EXAMPLE STENCIL DESIGN**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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